



MAP9004E/D

High Voltage AC LED Driver

MAP9004E/D – High Voltage AC LED Driver

General Description

The MAP9004E/D is LED Driver which has high input voltage ranged from 90V to 270V. It can drive several series LEDs from rectified AC voltage.

The MAP9004E/D has higher LED current drive capability up to 240mA and the current can be adjustable with external resistors.

The MAP9004E/D is available in eSOP-8 and DFN-33 4LD with Halogen-free (fully RoHS compliant).

For more information, please contact local MagnaChip sales office in world-wide or visit MagnaChip's website.

Features

- Wide operating voltage range
- Higher current drive capability
- Multiple connection for better efficiency, PF & THD
- EMI improvement
- OTP protection
- eSOP-8/DFN-33 4LD package

Applications

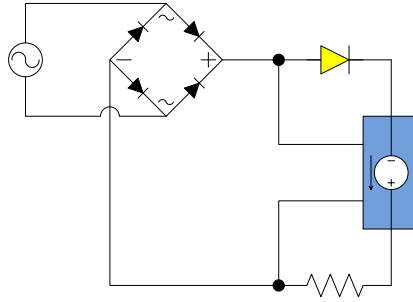
- AC LED Driver
- Lighting equipment
- LED Driver Power Supplies

Ordering Information

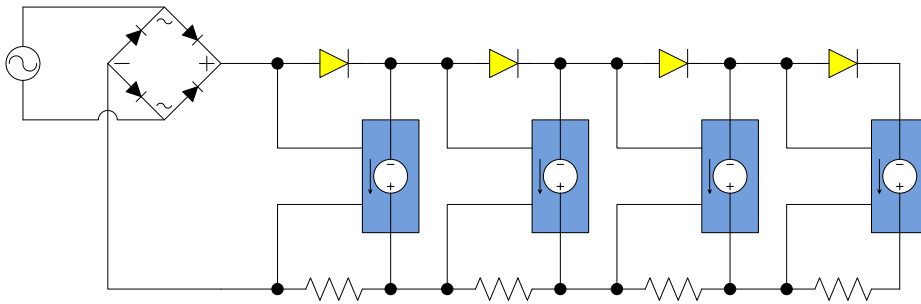
| Part Number | Top Marking | Ambient Temperature Range | Package | RoHS Status |
|-------------|-------------|---------------------------|------------|--------------|
| MAP9004ESRH | MAP9004E | -30℃ to +85℃ | eSOP-8 | Halogen Free |
| MAP9004DFRH | MAP9004D | -30℃ to +85℃ | DFN-33 4LD | Halogen Free |

Simplified Application Circuit

- Single Stage

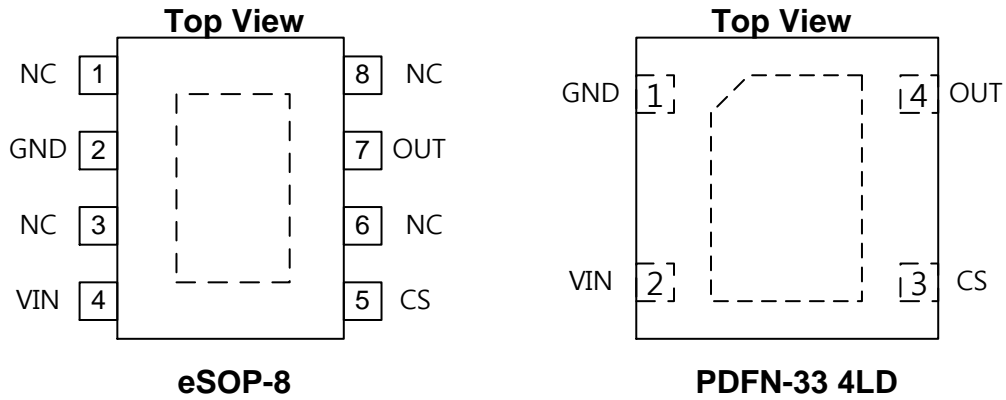


- Multi Stages for Better Efficiency, PF & THD



Pin Configuration & Description

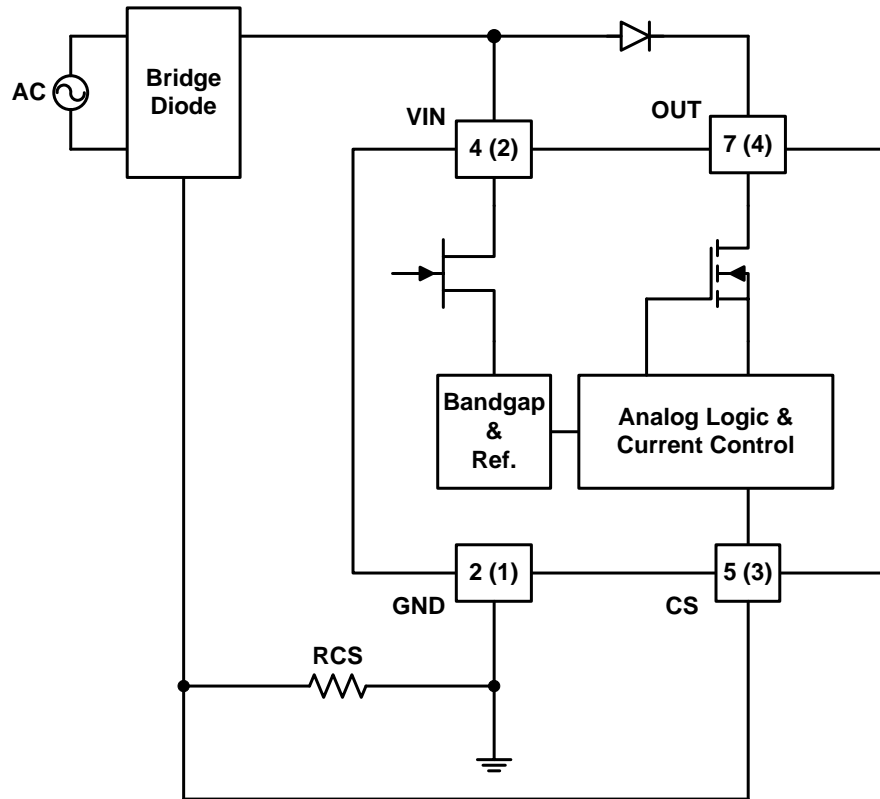
- Pin Configuration



- Pin Description

| Pin (PDFN-33) | | Descriptions |
|---------------|-----|-----------------|
| 2 (1) | GND | Ground |
| 4 (2) | VIN | Voltage input |
| 5 (3) | CS | Current sensing |
| 7 (4) | OUT | Output |

Functional Block Diagram



Absolute Maximum Ratings

| PARAMETER | | VALUE | UNIT |
|-------------------------------------|--------------|------------|------|
| VIN | | 500 | V |
| OUT | | -0.3 ~ 500 | V |
| CS | | -6V ~ 0.3 | V |
| Operating Temperature Range | | -40 ~ 125 | °C |
| Junction Temperature Range | | -40 ~ 150 | °C |
| Storage Temperature Range | | -65 ~ 150 | °C |
| Lead temperature(soldering, 10sec) | | 260 | °C |
| ESD Susceptibility | HBM (Note 1) | 4000 | V |
| | MM (Note 2) | 400 | V |
| | CDM (Note 3) | 2000 | V |

Note 1: ESD tested per JESD22A-114.

Note 2: ESD tested per JESD22A-115.

Note 3: ESD tested per JESD22C-101E

Thermal Resistance

| PARAMETER | | VALUE | UNIT |
|--|------------|-------|------|
| Thermal Resistance (θ_{JA}) , (Note4) | eSOP-8 | 71.2 | °C/W |
| | DFN-33 4LD | 65.9 | |
| Thermal Resistance (θ_{JT}) , (Note5) | eSOP-8 | 26.1 | |
| | DFN-33 4LD | 23.1 | |

Note 4: Multi-layer PCB based on JEDEC standard (JESD51-7, 4Layer PCB)

Note 5: The metal PCB's diameter is 43mm and height is 1.6t

Electrical Characteristics

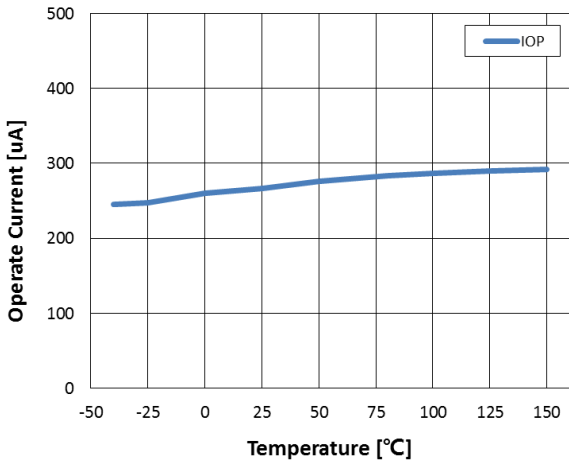
Ta = 25°C, CS Resistance = 6.8Ω unless otherwise specified

| SYMBOL | PARAMETER | TEST CONDITION | MIN | TYP | MAX | UNIT |
|-----------------------|-----------------------------|--|-----|-----|-----|------|
| Supply | | | | | | |
| V _{VIN_MIN} | Minimum Startup Voltage | | | | 25 | V |
| I _{VIN} | Input current | V _{VIN} = 200V, V _{GN} D = 0V | 150 | 350 | 700 | uA |
| Driver Section | | | | | | |
| I _{D Leak} | Driver leakage current | V _{VIN} = 0V, V _{GN} D = 0V, OUT = 400V | - | - | 10 | uA |
| I _{OUT} | Driver current | V _{VIN} = 200V, OUT = 40V | 180 | 185 | 190 | mA |
| OTP Section | | | | | | |
| OTP | Over temperature protection | | 150 | - | - | °C |

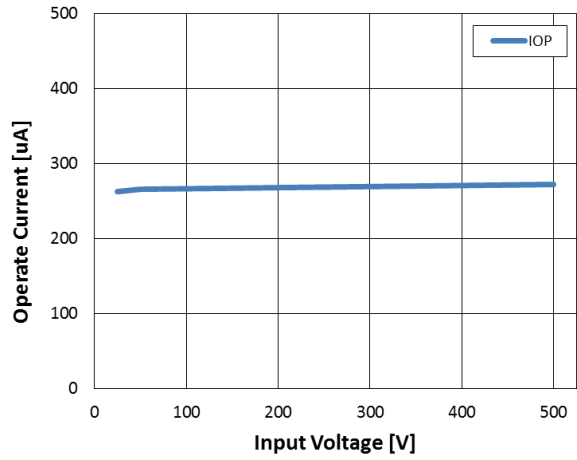
Note 6: Stress beyond the maximum ratings listed above may incur permanent damage to the device. Operating above the recommended conditions for extended time may stress the device and affect device reliability. Also the device may not operate normally above the recommended operating conditions. These are stress ratings only.

Typical Operating Characteristics (eSOP-8)

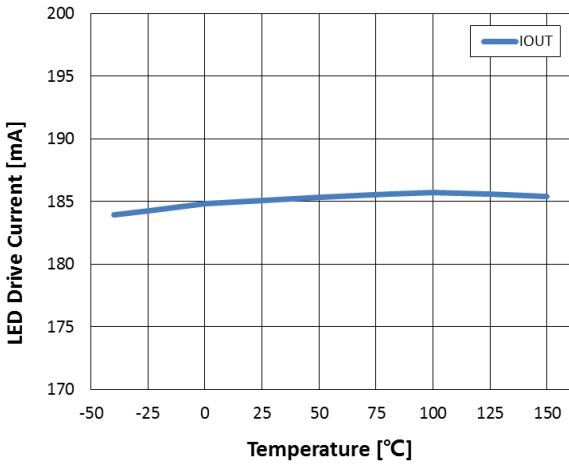
Operate Current Vs. Temperature



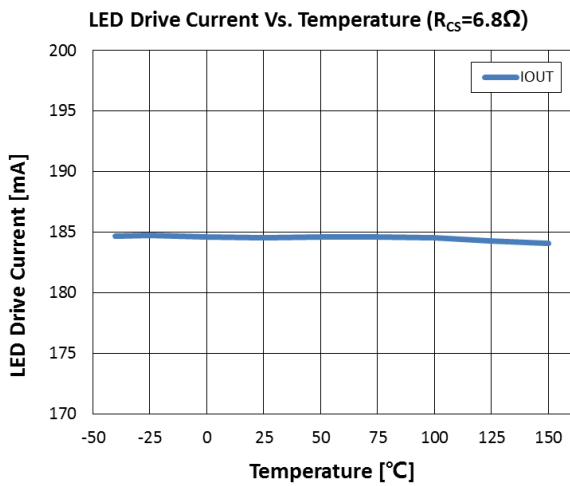
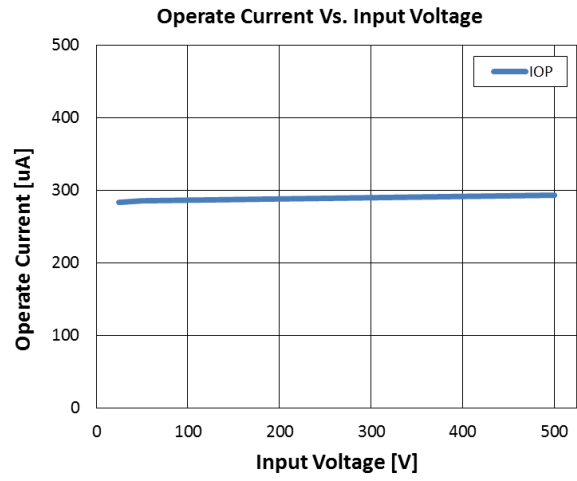
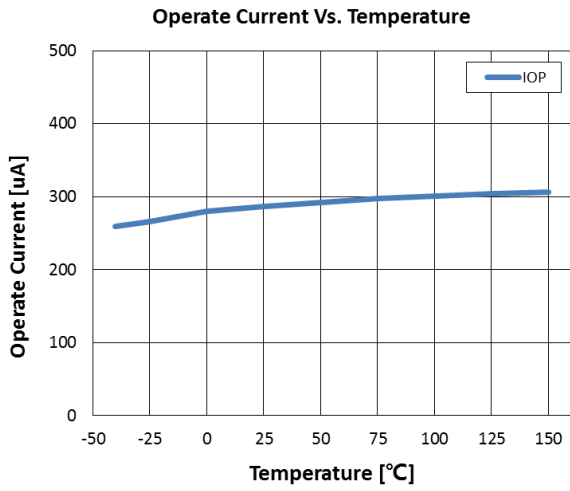
Operate Current Vs. Input Voltage



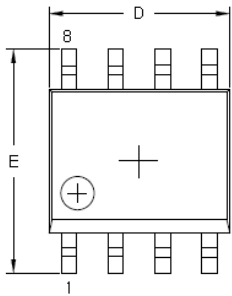
LED Drive Current Vs. Temperature ($R_{CS}=6.8\Omega$)



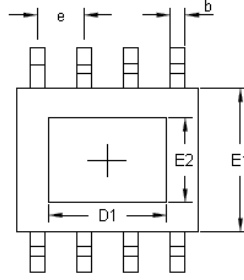
Typical Operating Characteristics (DFN33- 4LD)



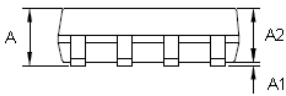
Physical Dimensions (eSOP-8)



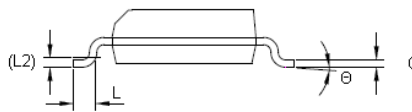
TOP VIEW



BOTTOM VIEW



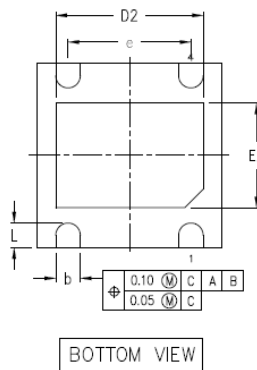
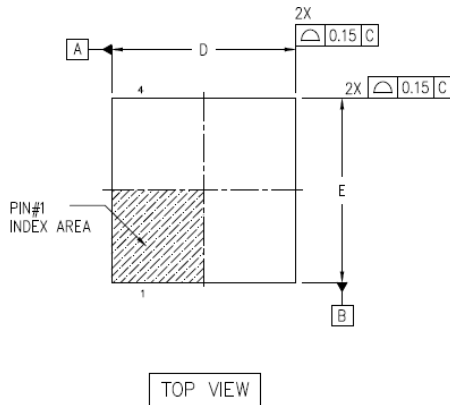
FRONT VIEW



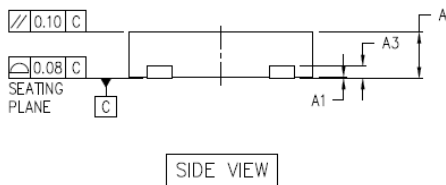
SIDE VIEW

| Symbol | Dimension [mm] | |
|--------|-------------------|------|
| | min | max |
| A | - | 1.70 |
| A1 | 0.00 | 0.15 |
| A2 | 1.25 | - |
| b | 0.31 | 0.51 |
| c | 0.10 | 0.25 |
| D | 4.90 BSC | |
| D1 | 2.95 | 3.35 |
| E | 6.00 BSC | |
| E1 | 3.90 BSC | |
| E2 | 2.05 | 2.45 |
| e | 1.27 BSC | |
| θ | 0° | 8° |
| L | 0.40 | 1.27 |
| L2 | 0.25(GAUGE PLANE) | |

Physical Dimensions (DFNX3 - 4LD)



| Symbol | Dimension (mm) | | |
|--------|----------------|------|------|
| | Min | Norm | Max |
| A | 0.70 | 0.75 | 0.80 |
| A1 | 0.00 | 0.02 | 0.05 |
| A3 | 0.20 REF. | | |
| D | 2.85 | 3.00 | 3.15 |
| E | 2.85 | 3.00 | 3.15 |
| D2 | 2.30 | 2.40 | 2.50 |
| E2 | 1.60 | 1.70 | 1.80 |
| b | 0.30 | 0.40 | 0.45 |
| e | 2.00 BSC | | |
| L | 0.30 | 0.40 | 0.50 |



MagnaChip Semiconductor Ltd. doesn't not recommend the use of its products in hostile environments, including, without limitation, aircraft, nuclear power generation, medical appliances, and devices or systems in which malfunction of any product can reasonably be expected to result in a personal injury. Seller's customers using or selling Seller's products for use in such applications do so at their own risk and agree to fully defend and indemnify Seller.

MagnaChip reserves the right to change the specifications and circuitry without notice at any time. **MagnaChip** does not consider responsibility for use of any circuitry other than circuitry entirely included in a **MagnaChip** product.

MagnaChip[®] is a registered trademark of MagnaChip Semiconductor Ltd.

MagnaChip Semiconductor Ltd.

891, Daechi-Dong, Kangnam-Gu, Seoul, 135-738 Korea

Tel : 82-2-6903-3451 / Fax : 82-2-6903-3668 ~9

Revision History

| Revision | History |
|----------|--|
| 0.0 | Preliminary Datasheet Initial Release |
| 0.1 | Update Thermal Resistance of DFN33 - $\theta_{JA} = 49\text{ }^{\circ}\text{C/W} \rightarrow 65.9\text{ }^{\circ}\text{C/W}$ - $\theta_{JT} = 26.1\text{ }^{\circ}\text{C/W} \rightarrow 23.1\text{ }^{\circ}\text{C/W}$ Update Typical characteristics of eSOP-8 |
| 0.2 | Update Typical characteristics of DFN33 4LD |
| 0.3 | Change I_{D_Leak} condition - $V_{VIN}=200V \rightarrow V_{VIN}=0V$ |
| 1.0 | Final Datasheet Initial Release |